



# SGM44599

## 4Ω, High Speed, Low Voltage Dual, DPDT Analog Switch

### GENERAL DESCRIPTION

The SGM44599 is a high-speed, low-voltage, advanced dual-independent double-pole/double-throw (DPDT) CMOS analog switch that is designed to operate from a single +1.8V to +5.5V power supply. It features high-bandwidth (300MHz) and low on-resistance (4Ω TYP).

The SGM44599 is configured as a dual double-pole/double-throw (DPDT) device with two logic control inputs that control two multiplexer/demultiplexer each. The configuration can also be used as a dual differential 2-to-1 multiplexer/ demultiplexer.

SGM44599 is available in Green TQFN-3×3-16L and TQFN-2.5×2.5-16L packages.

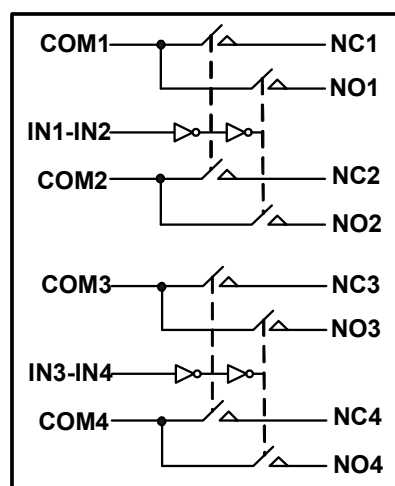
### APPLICATIONS

- Communication Systems
- Cell Phones
- Portable Instrumentation
- Audio Signal Routing
- Audio and Video Switching
- PCMCIA Cards
- Computer Peripherals
- Modems
- PDA's

### FEATURES

- Low Voltage Operation: 1.8V to 5.5V
- On-Resistance: 4Ω (TYP)
- Low On-Resistance Flatness
- -3dB Bandwidth: 300MHz
- Rail-to-Rail Input and Output Operation
- High Off-Isolation: -75dB at 1MHz
- Low Crosstalk: -100dB at 1MHz
- Typical Power Consumption (<0.01μW)
- TTL/CMOS Compatible
- Available in Green TQFN-3×3-16L and TQFN-2.5×2.5-16L Packages
- Extended Industrial Temperature Range: -40°C to +85°C

### BLOCK DIAGRAM



**PACKAGE/ORDERING INFORMATION**

MODEL	PIN-PACKAGE	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKAGE OPTION
SGM44599	TQFN-3×3-16L	-40°C to +85°C	SGM44599YTQ16/TR	44599	Tape and Reel, 3000
	TQFN-2.5×2.5-16L	-40°C to +85°C	SGM44599YTQB16/TR	44599	Tape and Reel, 3000

**ABSOLUTE MAXIMUM RATINGS**

V <sub>+</sub> to GND.....	-0.3V to 6V
Analog, Digital voltage range.....	-0.3V to (V <sub>+</sub> ) + 0.3V
Continuous Current NO, NC, or COM .....	±100mA
Operating Temperature Range.....	-40°C to +85°C
Junction Temperature.....	150°C
Storage Temperature.....	-65°C to +150°C
Lead Temperature (soldering, 10s).....	260°C
ESD Susceptibility	
HBM.....	2000V
MM.....	200V

**NOTE:**

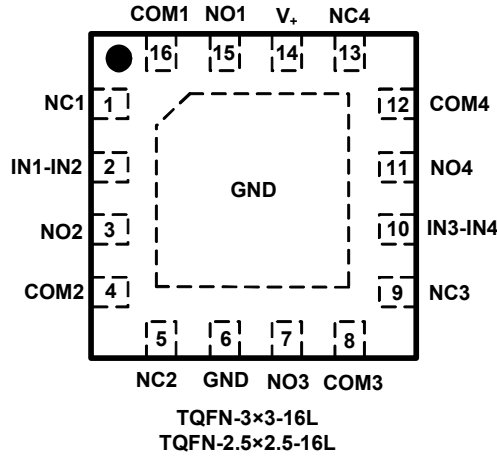
Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**CAUTION**

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

SGMICRO reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time. Please contact SGMICRO sales office to get the last datasheet.

**PIN CONFIGURATIONS (TOP VIEW)**



**PIN DESCRIPTION**

NAME	PIN		FUNCTION
	TQFN-3×3-16L	TQFN-2.5×2.5-16L	
V <sub>+</sub>	14		Power supply
GND	6		Ground
IN <sub>x</sub>	2, 10		Digital control pin to connect the COM terminal to the NO or NC terminals
COM <sub>x</sub>	16, 4, 8, 12		Common terminal
NO <sub>x</sub>	15, 3, 7, 11		Normally-open terminal
NC <sub>x</sub>	1, 5, 9, 13		Normally-closed terminal

NOTE: NO<sub>x</sub>, NC<sub>x</sub> and COM<sub>x</sub> terminals may be an input or output.

**FUNCTION TABLE**

IN1-IN2	FUNCTION	
	NC1 and NC2	NO1 and NO2
0	ON	OFF
1	OFF	ON

IN3-IN4	FUNCTION	
	NC3 and NC4	NO3 and NO4
0	ON	OFF
1	OFF	ON

**ELECTRICAL CHARACTERISTICS**

( $V_+ = +4.5V$  to  $+5.5V$ ,  $GND = 0V$ ,  $V_{IH} = +1.6V$ ,  $V_{IL} = +0.5V$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$ . Typical values are at  $V_+ = +5.0V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
<b>ANALOG SWITCH</b>							
Analog Signal Range	$V_{NO}, V_{NC}, V_{COM}$		$-40^\circ C$ to $+85^\circ C$	0		$V_+$	V
On-Resistance	$R_{ON}$	$V_+ = 4.5V, 0V \leq V_{NO}$ or $V_{NC} \leq V_+, I_{COM} = -100mA$ , Test Circuit 1	$+25^\circ C$		4	6.2	$\Omega$
			$-40^\circ C$ to $+85^\circ C$			7.2	$\Omega$
On-Resistance Match Between Channels	$\Delta R_{ON}$	$V_+ = 4.5V, 0V \leq V_{NO}$ or $V_{NC} \leq V_+, I_{COM} = -100mA$ , Test Circuit 1	$+25^\circ C$		0.4	2.6	$\Omega$
			$-40^\circ C$ to $+85^\circ C$			3.1	$\Omega$
On-Resistance Flatness	$R_{FLAT(ON)}$	$V_+ = 4.5V, 0V \leq V_{NO}$ or $V_{NC} \leq V_+, I_{COM} = -100mA$ , Test Circuit 1	$+25^\circ C$		2	3.1	$\Omega$
			$-40^\circ C$ to $+85^\circ C$			3.6	$\Omega$
Source OFF Leakage Current	$I_{NC(OFF)}, I_{NO(OFF)}$	$V_+ = 5.5V, V_{NO}$ or $V_{NC} = 3.3V/0.3V, V_{COM} = 0.3V/3.3V$	$-40^\circ C$ to $+85^\circ C$			1	$\mu A$
Channel ON Leakage Current	$I_{NC(ON)}, I_{NO(ON)}, I_{COM(ON)}$	$V_+ = 5.5V, V_{COM} = 0.3V/3.3V, V_{NO}$ or $V_{NC} = 0.3V/3.3V$ , or floating	$-40^\circ C$ to $+85^\circ C$			1	$\mu A$
<b>DIGITAL INPUTS</b>							
Input High Voltage	$V_{INH}$		$-40^\circ C$ to $+85^\circ C$	1.6			V
Input Low Voltage	$V_{INL}$		$-40^\circ C$ to $+85^\circ C$			0.5	V
Input Leakage Current	$I_{IN}$	$V_+ = 5.5V, V_{IN} = 0V$ or $5.5V$	$-40^\circ C$ to $+85^\circ C$			1	$\mu A$
<b>DYNAMIC CHARACTERISTICS</b>							
Turn-On Time	$t_{ON}$	$V_{NC}$ or $V_{NO} = 3.0V, R_L = 300\Omega, C_L = 35pF$ , Test Circuit2	$+25^\circ C$		31.5		ns
Turn-Off Time	$t_{OFF}$		$+25^\circ C$		30.0		ns
Break-Before-Make Time Delay	$t_D$	$V_{NC}$ or $V_{NO} = 3.0V, R_L = 300\Omega, C_L = 35pF$ , Test Circuit4	$+25^\circ C$		11.5		ns
Charge Injection	Q	$V_G = GND, R_G = 0\Omega, C_L = 1.0nF, Q = C_L \times V_{OUT}$ , Test Circuit3	$+25^\circ C$		3.5		pC
Off Isolation	$O_{ISO}$	Signal = 0dBm, $R_L = 50\Omega$ , Test Circuit5	1MHz	$+25^\circ C$		-75	dB
			10MHz	$+25^\circ C$		-55	
Channel-to-Channel Crosstalk	$X_{TALK}$	Signal = 0dBm, $R_L = 50\Omega$ , Test Circuit6	1MHz	$+25^\circ C$		-100	dB
			10MHz	$+25^\circ C$		-60	
-3dB Bandwidth	BW	Signal = 0dBm, $R_L = 50\Omega$ , Test Circuit7	$+25^\circ C$		300		MHz
Channel ON Capacitance	$C_{NC(ON)}, C_{NO(ON)}, C_{COM(ON)}$		$+25^\circ C$		43.2		pF
<b>POWER REQUIREMENTS</b>							
Power Supply Range	$V_+$		$-40^\circ C$ to $+85^\circ C$	1.8		5.5	V
Power Supply Current	$I_+$	$V_+ = 5.5V, V_{IN} = 0V$ or $V_+$	$-40^\circ C$ to $+85^\circ C$			1	$\mu A$

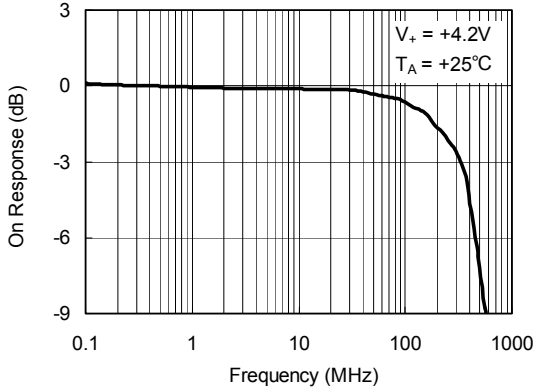
**ELECTRICAL CHARACTERISTICS**

( $V_+ = +2.7V$  to  $+3.6V$ ,  $V_{IH} = +1.6V$ ,  $V_{IL} = +0.4V$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$ . Typical values are at  $V_+ = +3.0V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

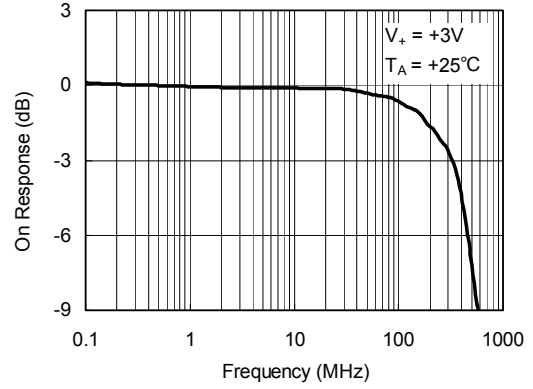
PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
<b>ANALOG SWITCH</b>							
Analog Signal Range	$V_{NO}, V_{NC}, V_{COM}$		$-40^\circ C$ to $+85^\circ C$	0		$V_+$	V
On-Resistance	$R_{ON}$	$V_+ = 2.7V, 0V \leq V_{NO}$ or $V_{NC} \leq V_+$ , $I_{COM} = -100mA$ , Test Circuit 1	$+25^\circ C$		10	15	$\Omega$
			$-40^\circ C$ to $+85^\circ C$			18	$\Omega$
On-Resistance Match Between Channels	$\Delta R_{ON}$	$V_+ = 2.7V, 0V \leq V_{NO}$ or $V_{NC} \leq V_+$ , $I_{COM} = -100mA$ , Test Circuit 1	$+25^\circ C$		1	3	$\Omega$
			$-40^\circ C$ to $+85^\circ C$			4	$\Omega$
On-Resistance Flatness	$R_{FLAT(ON)}$	$V_+ = 2.7V, 0V \leq V_{NO}$ or $V_{NC} \leq V_+$ , $I_{COM} = -100mA$ , Test Circuit 1	$+25^\circ C$		6	9	$\Omega$
			$-40^\circ C$ to $+85^\circ C$			12	$\Omega$
Source OFF Leakage Current	$I_{NC(OFF)}, I_{NO(OFF)}$	$V_+ = 3.6V, V_{NO}$ or $V_{NC} = 3.3V / 0.3V$ , $V_{COM} = 0.3V / 3.3V$	$-40^\circ C$ to $+85^\circ C$			1	$\mu A$
Channel ON Leakage Current	$I_{NC(ON)}, I_{NO(ON)}, I_{COM(ON)}$	$V_+ = 3.6V, V_{COM} = 0.3V / 3.3V$ , $V_{NO}$ or $V_{NC} = 0.3V / 3.3V$ , or floating	$-40^\circ C$ to $+85^\circ C$			1	$\mu A$
<b>DIGITAL INPUTS</b>							
Input High Voltage	$V_{INH}$		$-40^\circ C$ to $+85^\circ C$	1.5			V
Input Low Voltage	$V_{INL}$		$-40^\circ C$ to $+85^\circ C$			0.4	V
Input Leakage Current	$I_{IN}$	$V_+ = 2.7V, V_{IN} = 0V$ or $2.7V$	$-40^\circ C$ to $+85^\circ C$			1	$\mu A$
<b>DYNAMIC CHARACTERISTICS</b>							
Turn-On Time	$t_{ON}$	$V_{NC}$ or $V_{NO} = 1.5V, R_L = 300\Omega$ , $C_L = 35pF$ , Test Circuit2	$+25^\circ C$		38.0		ns
Turn-Off Time	$t_{OFF}$		$+25^\circ C$		44.0		ns
Break-Before-Make Time Delay	$t_D$	$V_{NC}$ or $V_{NO} = 1.5V, R_L = 300\Omega$ , $C_L = 35pF$ , Test Circuit4	$+25^\circ C$		5.8		ns
Charge Injection	Q	$V_G = GND, R_G = 0\Omega, C_L = 1.0nF$ , $Q = C_L \times V_{OUT}$ , Test Circuit3	$+25^\circ C$		2.6		pC
Off Isolation	$O_{ISO}$	Signal = 0dBm, $R_L = 50\Omega$ , Test Circuit5	1MHz	$+25^\circ C$		-75	dB
			10MHz	$+25^\circ C$		-55	dB
Channel-to-Channel Crosstalk	$X_{TALK}$	Signal = 0dBm, $R_L = 50\Omega$ , Test Circuit6	1MHz	$+25^\circ C$		-100	dB
			10MHz	$+25^\circ C$		-60	dB
-3dB Bandwidth	BW	Signal = 0dBm, $R_L = 50\Omega$ , Test Circuit7	$+25^\circ C$		300		MHz
Channel ON Capacitance	$C_{NC(ON)}, C_{NO(ON)}, C_{COM(ON)}$		$+25^\circ C$		43.2		pF

TYPICAL PERFORMANCE CHARACTERISTICS

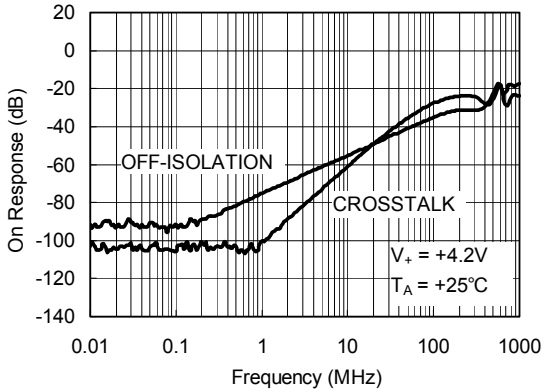
On Response vs. Frequency



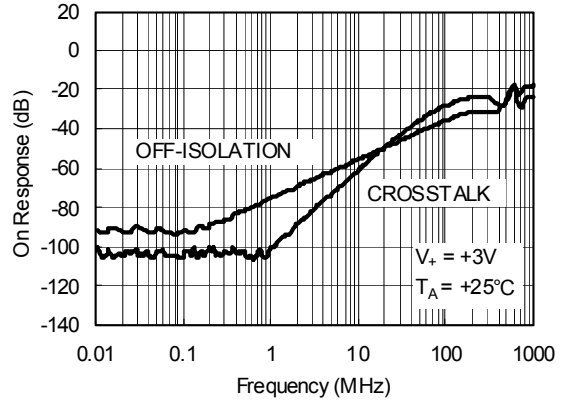
On Response vs. Frequency



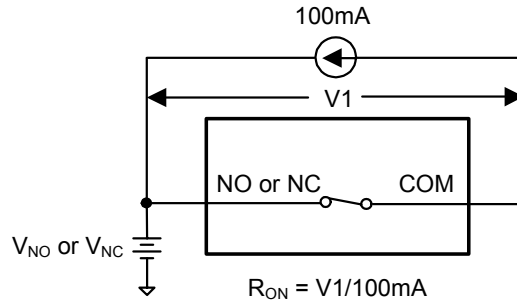
Response vs. Frequency



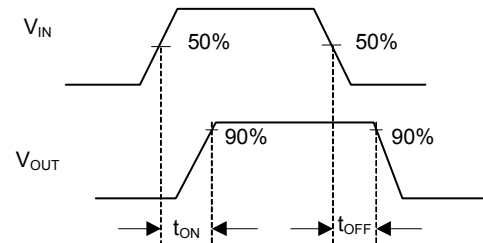
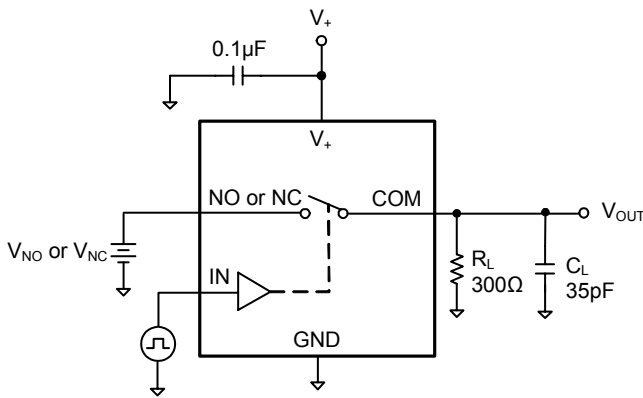
Response vs. Frequency



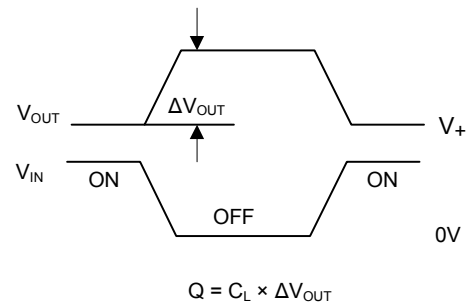
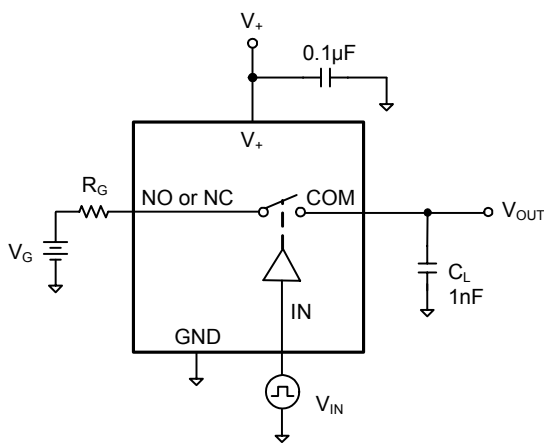
TEST CIRCUITS



Test Circuit 1. On Resistance

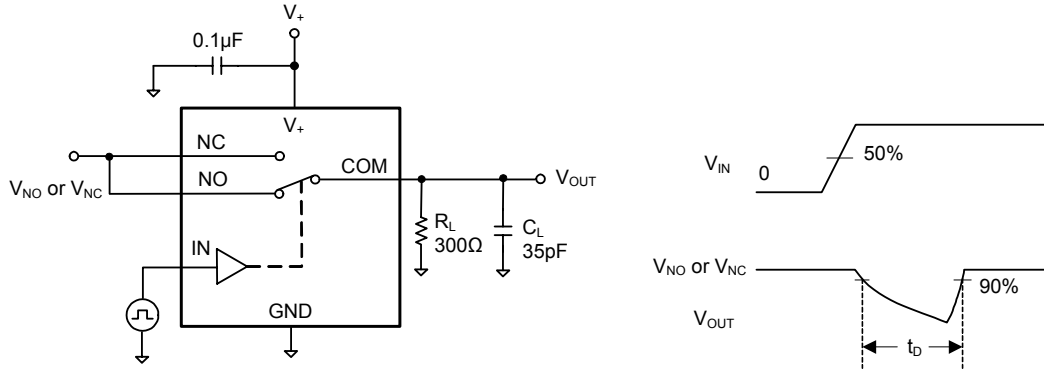


Test Circuit 2. Switching Times ( $t_{ON}$ ,  $t_{OFF}$ )

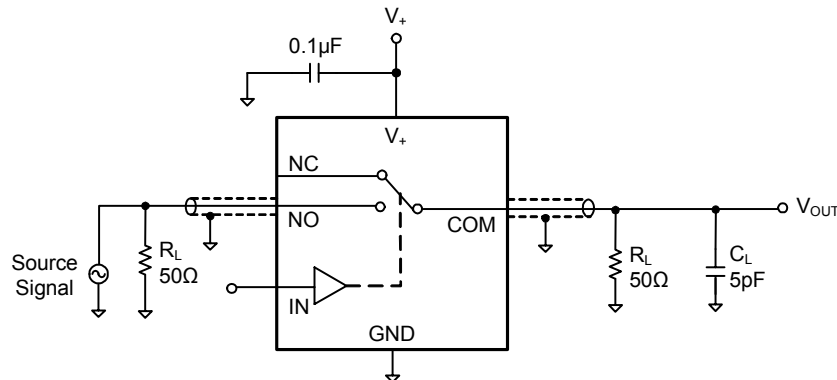


Test Circuit 3. Charge Injection

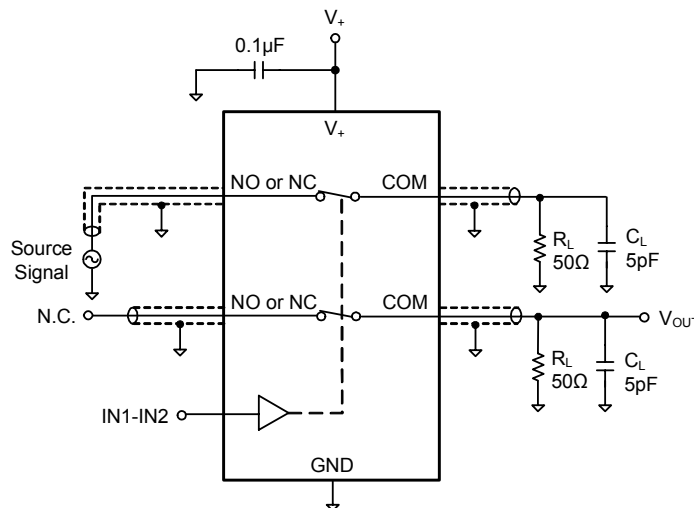
TEST CIRCUITS (Cont.)



Test Circuit 4. Break-Before-Make Time Delay ( $t_d$ )



Test Circuit 5. Off Isolation

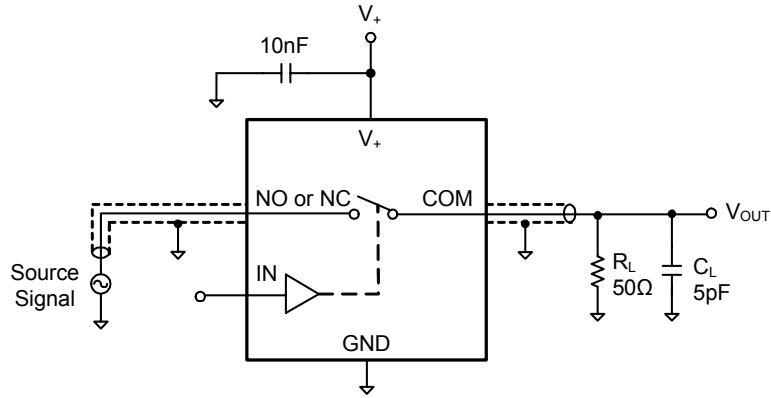


$$\text{Channel To Channel Crosstalk} = -20 \times \log \frac{V_{NO \text{ or } V_{NC}}}{V_{OUT}}$$

Test Circuit 6. Channel-to-Channel Crosstalk



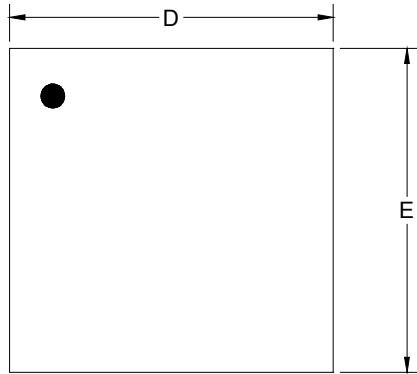
TEST CIRCUITS (Cont.)



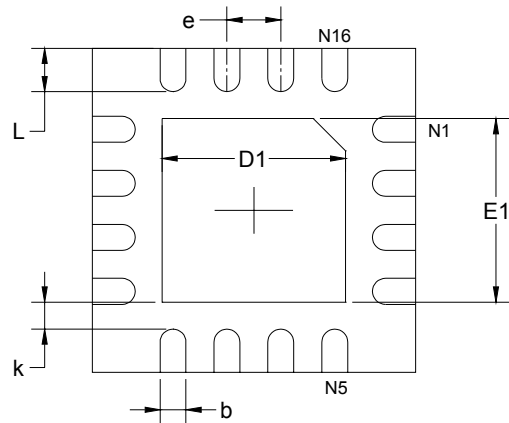
Test Circuit 7. -3dB Bandwidth

PACKAGE OUTLINE DIMENSIONS

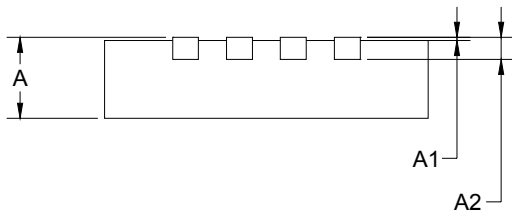
TQFN-3×3-16L



TOP VIEW



BOTTOM VIEW

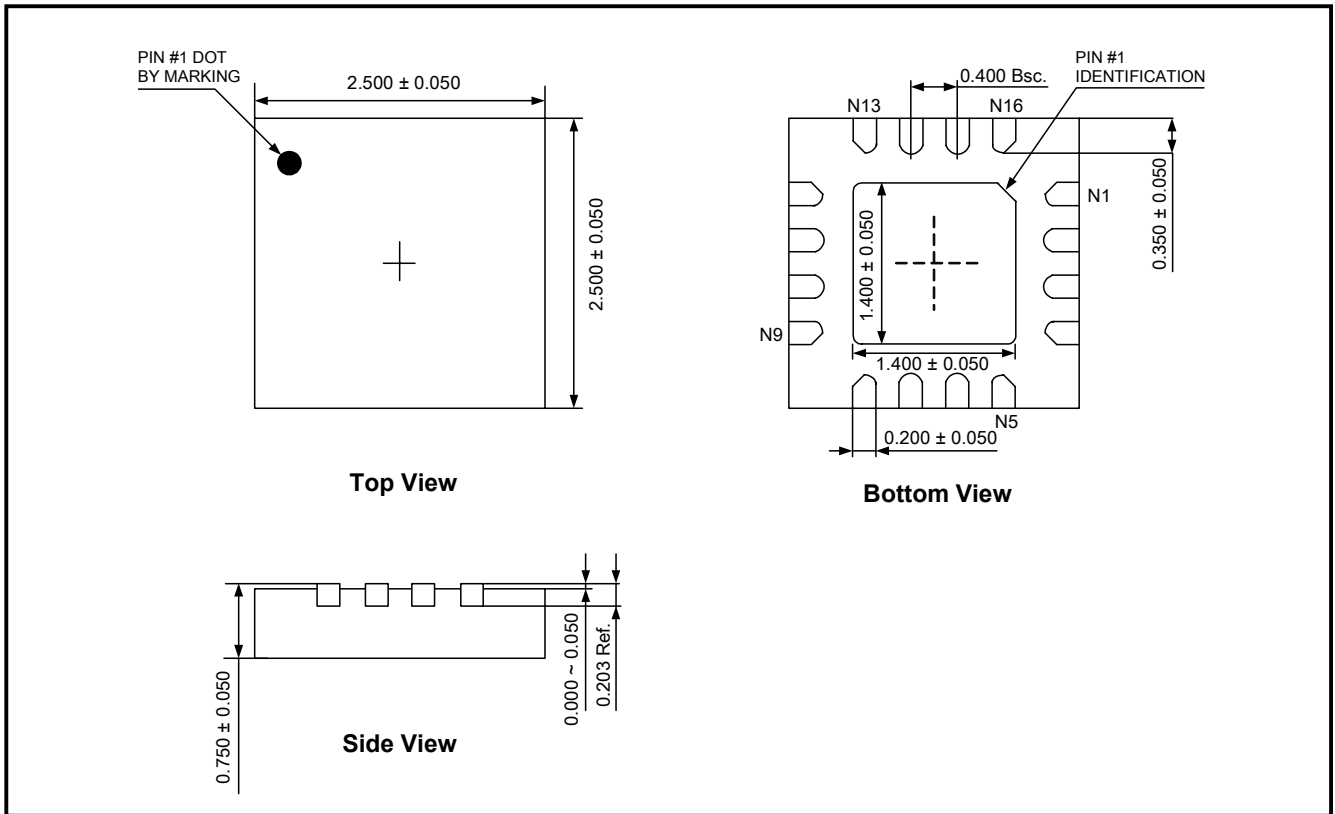


SIDE VIEW

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A2	0.203 REF		0.008 REF	
D	2.900	3.100	0.114	0.122
D1	1.600	1.800	0.063	0.071
E	2.900	3.100	0.114	0.122
E1	1.600	1.800	0.063	0.071
k	0.200 MIN		0.008 MIN	
b	0.180	0.300	0.007	0.012
e	0.500 TYP		0.020 TYP	
L	0.300	0.500	0.012	0.020

PACKAGE OUTLINE DIMENSIONS

TQFN-2.5×2.5-16L



NOTE: All linear dimensions are in millimeters.